

30A SCHOTTKY BARRIER RECTIFIER

General Description

MBR3045CT Device optimized for ultra-low forward voltage drop to maximize efficiency in Power Supply applications.

Features

- Common Cathode
- Multilayer Metal -Silicon Potential Structure
- Have Over Voltage protect loop, high reliability
- RoHS Compliant

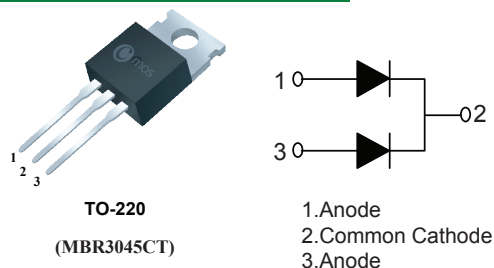
Product Summary

V_{RRM}	V_F	$I_{F(AV)}$
45V	0.66V	30A

Applications

- DC/DC converter
- Switched Mode Power Supplies (SMPS)
- Low Voltage High Frequency Invers Circuit

TO-220 Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{RRM}	Peak Repetitive Reverse Voltage	45	V
$I_{F(AV)}$	Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% duty cycle	15 (Per Leg) 30 (Total)	A
dv/dt	Voltage rate of change (Rated VR)	10000	V/uS
I_{RRM}	Peak Repetitive Reverse Surge Current (2uS,1Khz)	0.5	A
I_{FSM}	Forward Peak Surge Current(Rated Load 8.3ms Half Mssine Wave-According to JEDEC Method)	290*2	A
T_J	Operating Junction Temperature	150	°C
T_{STG}	Storage Temperature	-40 to 150	°C

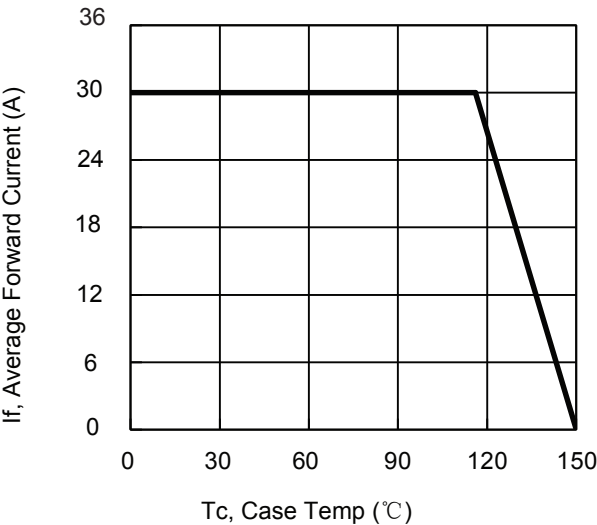
Thermal Data

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case(Per Leg)	2	---	°C/W

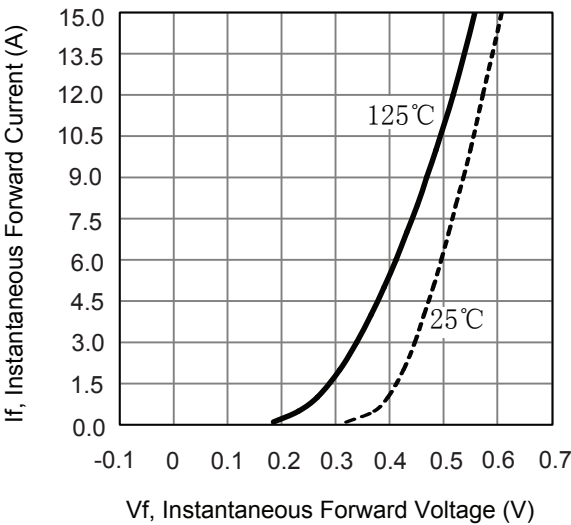
Electrical Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V _F	Forward Voltage Drop per diode	I _F =15A, T _C =25°C (I _{FAV} =15A*2)	---	0.61	0.66	V
		I _F =15A, T _C =125°C (I _{FAV} =15A*2)	---	---	0.60	
I _R	Reverse Leakage Current per diode	V _R =45V, T _C =25°C	---	---	0.05	mA
		V _R =45V, T _C =125°C	---	---	15.00	mA

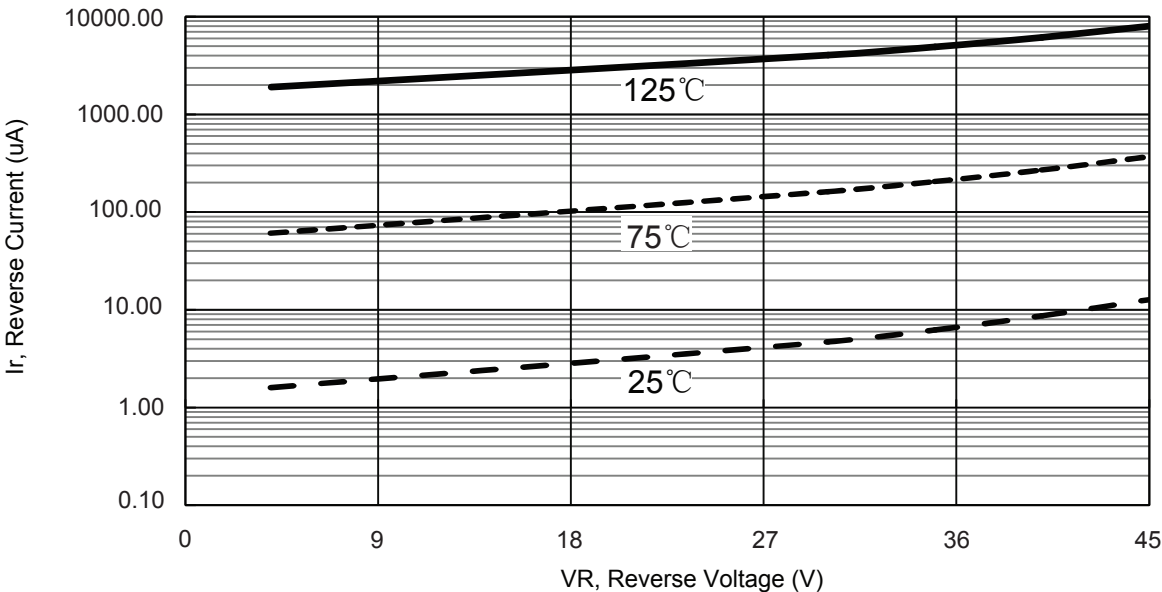
Typical Performance Characteristics



Current derating curve, per element



The forward voltage and forward current curve



The reverse leak current and the reverse voltage (single-device) curve

This product has been designed and qualified for the counsumer market.
Cmos assumes no liability for customers' product design or applications.
Cmos reserver the right to improve product design ,functions and reliability wihtout notice.